

# Power transistor (-60V, -3A)

# 2SA2071

#### Features

1) High speed switching. (Tf: Typ.: 20ns at Ic = -3A)

2) Low saturation voltage, typically

(Typ.: -200mV at Ic = -2A, IB = -0.2A)

- 3) Strong discharge power for inductive load and capacitance load.
- 4) Complements the 2SC5824

# Applications

Low Frequency Amplifier High speed switching

#### Structure

PNP Silicon epitaxial planar transistor

#### Packaging specifications

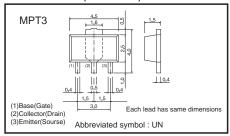
	Package	Taping
Туре	Code	T100
	Basic ordering unit (pieces)	1000
2SA2071		0

## ●Absolute maximum ratings (Ta=25°C)

Parameter	Symbol	Limits	Unit
Collector-base voltage	Vсво	-60	V
Collector-emitter voltage	Vceo	-60	V
Emitter-base voltage	Vево	-6	V
Collector current	Ic	-3	Α
Collector current	Іср	-6	A *1
Dower dissination	Pc	500	mW
Power dissipation	PC	2.0	W *2
Junction temperature	Tj	150	°C
Range of storage temperature	Tstg	-55 to +150	°C

<sup>\*1</sup> Pw=100ms

#### ●Dimensions (Unit: mm)



<sup>\*2</sup> Mounted on a 40×40×0.7 (mm) ceramic substrate

2SA2071 **Data Sheet** 

## ●Electrical characteristics (Ta=25°C)

Parameter	Symbol	Min.	Тур.	Max.	Unit	Conditions
Collector-base breakdown voltage	ВУсво	-60	_	_	V	Ic= -100μA
Collector-emitter breakdown voltage	BVceo	-60	_	_	V	Ic=-1mA
Emitter-base breakdown voltage	ВVево	-6	_	_	V	I <sub>E</sub> = -100μA
Collector cut-off current	Ісво	-	_	-1.0	μΑ	V <sub>CB</sub> = -40V
Emitter cut-off current	ІЕВО	_	_	-1.0	μΑ	V <sub>EB</sub> = -4V
Collector-emitter saturation voltage	VcE (sat)	_	-200	-500	mV	Ic= -2A, I <sub>B</sub> = -0.2A *1
DC current gain	hfe	120	_	270	_	VcE= -2V, Ic= -100mA
Transition frequency	f⊤	-	180	_	MHz	Vc=-10V, I=10mA, f=10MHz *1
Collector output capacitance	Cob	-	50	_	pF	Vcb= -10V, Ie=0mA, f=1MHz
Turn-on time	Ton	_	20	_	ns	Ic= -3A
Storage time	Tstg	_	150	_	ns	l <sub>B1</sub> = –300mA   l <sub>B2</sub> =300mA
Fall time	Tf	_	20	_	ns	Vcc ≒ –25V *2

#### ●hfe RANK

Q	
120–270	

#### •Electrical characteristic curves

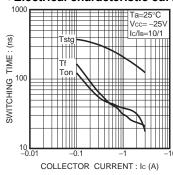


Fig.1 Switching Time

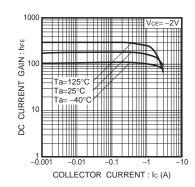


Fig.2 DC Current Gain vs. Collector Current (I)

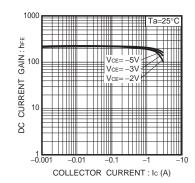


Fig.3 DC Current Gain vs. Collector Current (II)

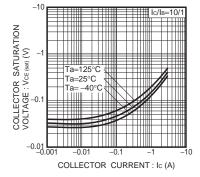


Fig.4 Collector-Emitter Saturation Voltage vs. Collector Current (I)

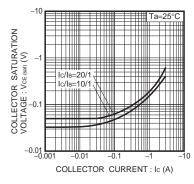


Fig.5 Collector-Emitter Saturation Voltage vs. Collector Current (II)

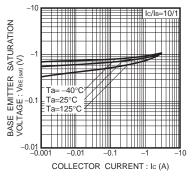


Fig.6 Base-Emitter Saturation Voltage vs. Collecter Current

<sup>\*1</sup> Non repetitive pulse \*2 See switching charactaristics measurement cicuits

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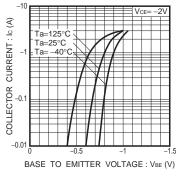


Fig.7 Grounded Emitter
Propagation Characteristics

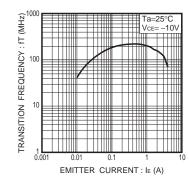


Fig.8 Transition Frequency

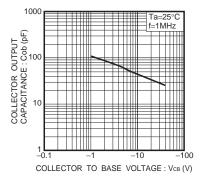
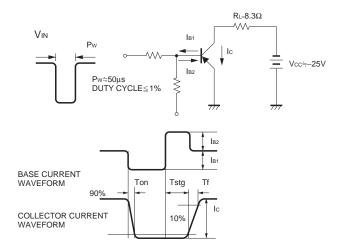


Fig.9 Collector Output Capacitance

# •Switching characteristics measurement circuits



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